Engineering of Semiconductor

:Semiconductor Physics and Devices

Chapter 2. Silicon Technology

Objectives

Overview of Silicon Technology

- Wafer preparation
- Oxidation
- Lithography
- Etching
- Doping
- Deposition
- Packaging

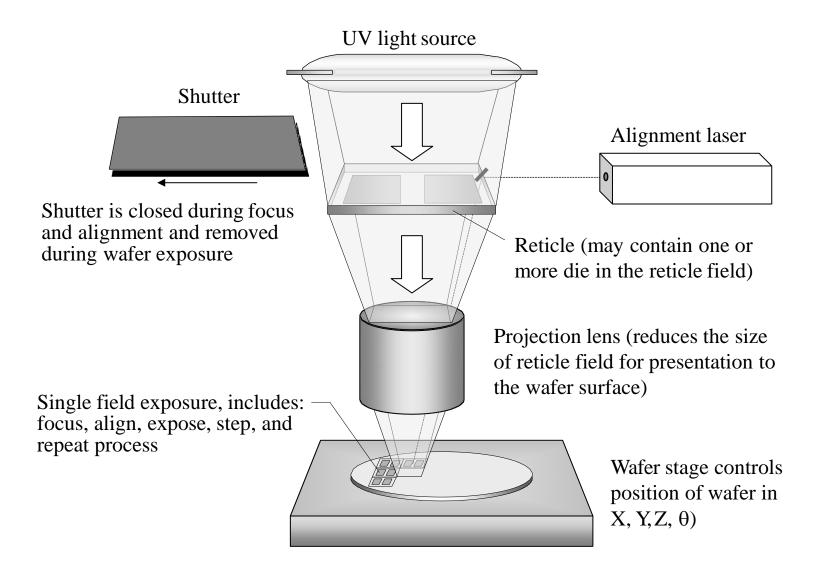
Eight Basic Steps of Photolithography

Step
1. Vapor prime
2. Spin coat
3. Soft bake
4. Alignment and exposure
5. Post-exposure bake
6. Develop
7. Hard bake
8. Develop inspect

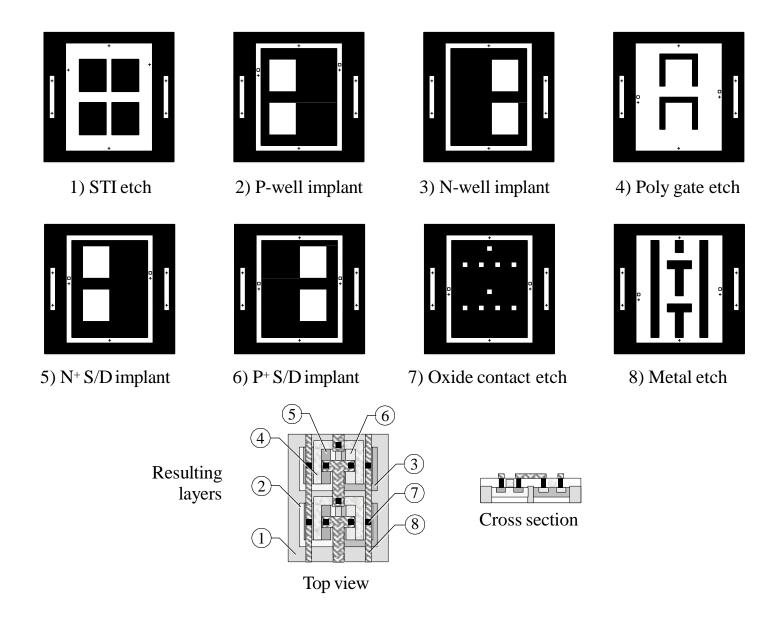
Three Functions of the Wafer Stepper

- 1. Focus and align the quartz plate reticle (that has the patterns) to the wafer surface.
- 2. Reproduce a high-resolution reticle image on the wafer through exposure of photoresist.
- 3. Produce an adequate quantity of acceptable wafers per unit time to meet production requirements.

Reticle Pattern Transfer to Resist



Layout and Dimensions of Reticle Patterns



Optical Lithography

Resolution

- Calculating Resolution
- Depth of Focus
- Resolution Versus Depth of Focus
 - Surface Planarity

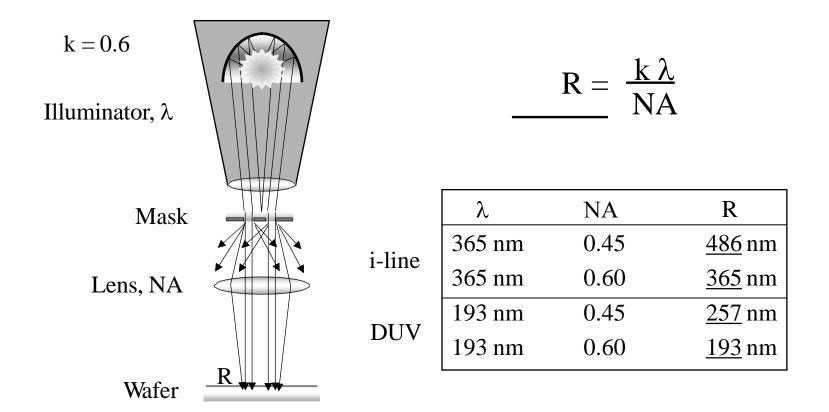
Resolution of Features





The dimensions of linewidths and spaces must be equal. As feature sizes decrease, it is more difficult to separate features from each other.

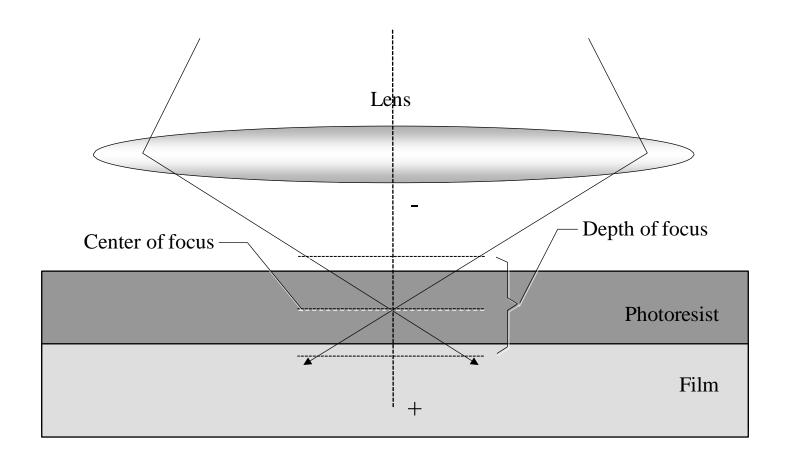
Calculating Resolution for a given λ , NA and k



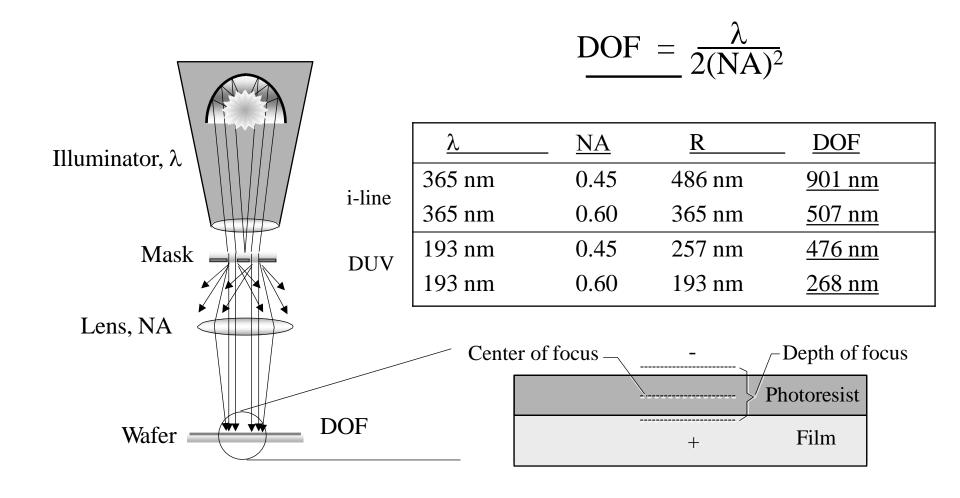
Numerical Aperture(NA):

In optics, the numerical aperture (NA) of an optical system is a dimensionless number that characterizes the range of angles over which the system can accept or emit light.

Depth of Focus (DOF)



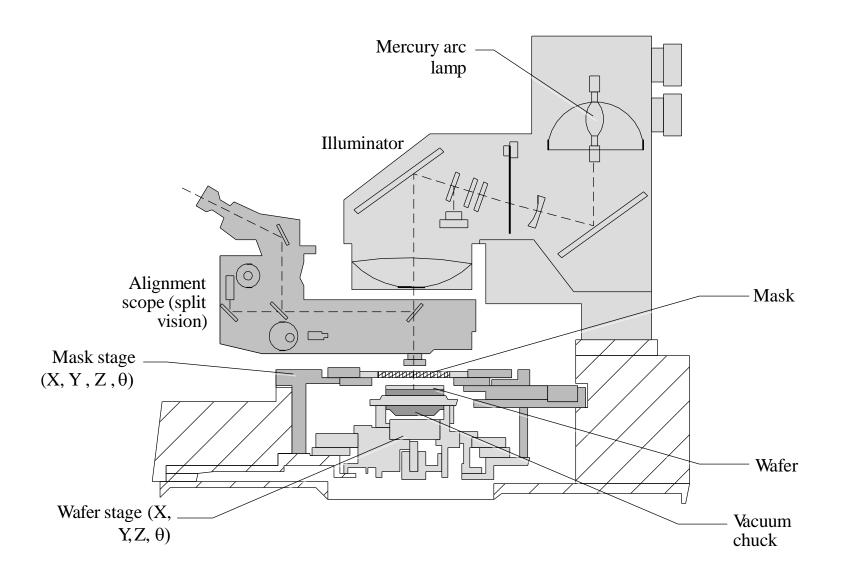
Resolution Versus Depth of Focus for Varying NA



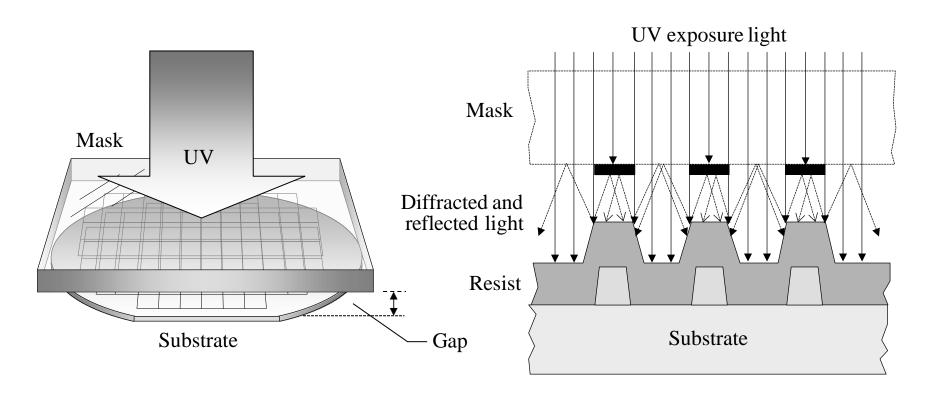
Photolithograhy Equipment

- Contact Aligner
- Proximity Aligner
- Scanning Projection Aligner (scanner)
- Step-and-Repeat Aligner (stepper)
- Step-and-Scan System

Contact/Proximity Aligner System

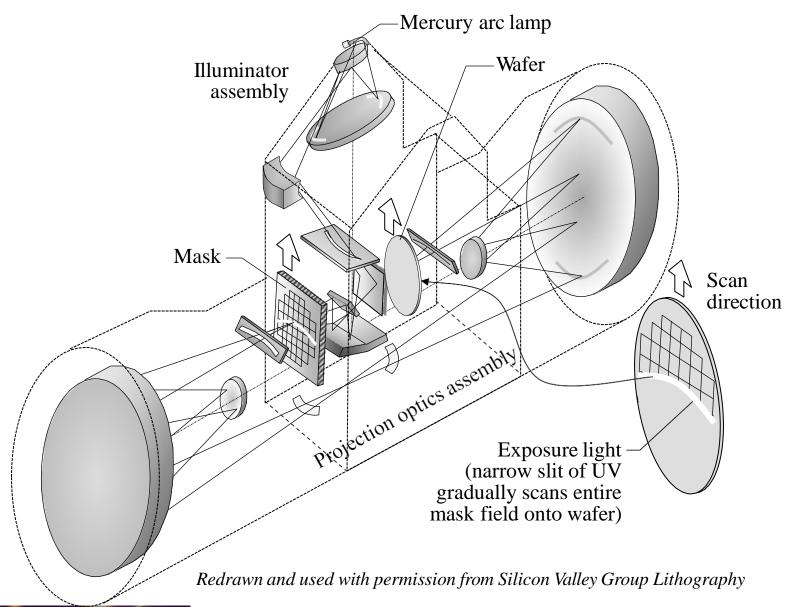


Edge Diffraction and Surface Reflectivity on Proximity Align er

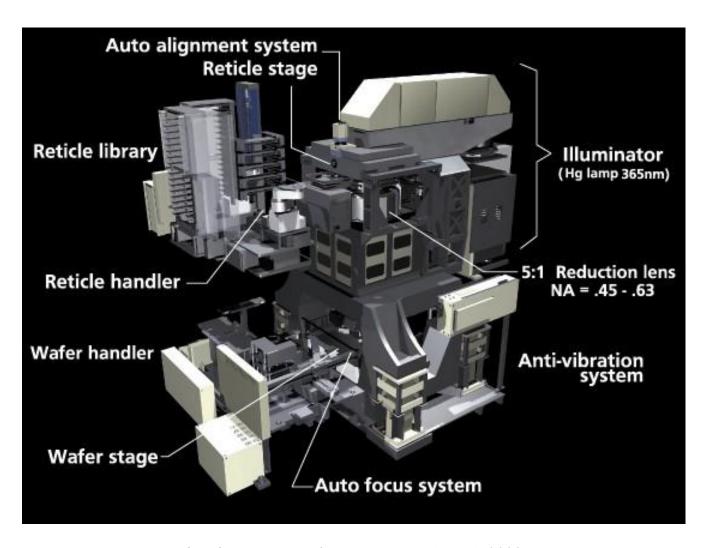


Diffraction of light on edges results in reflections from underside of mask causing undesirable resist exposure.

Scanning Projection Aligner

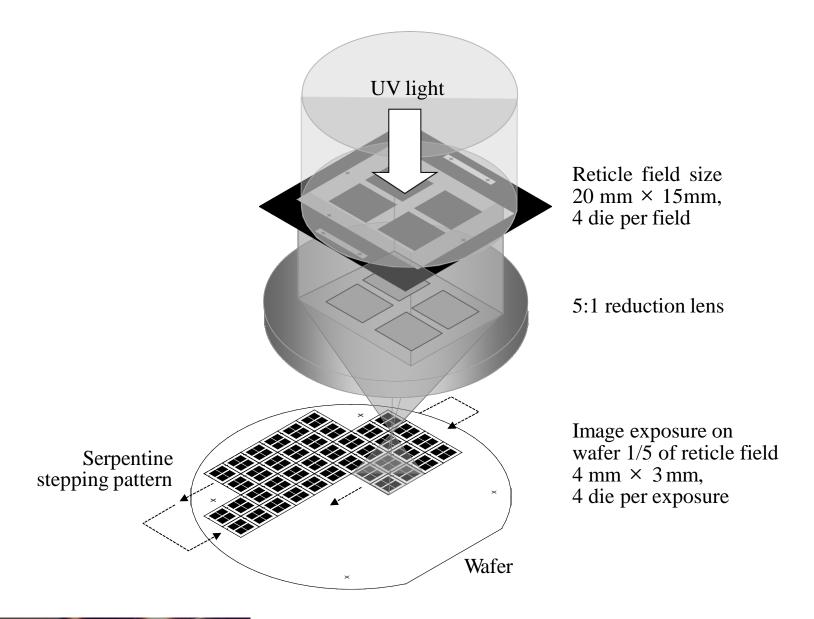


Step-and-Repeat Aligner (Stepper)

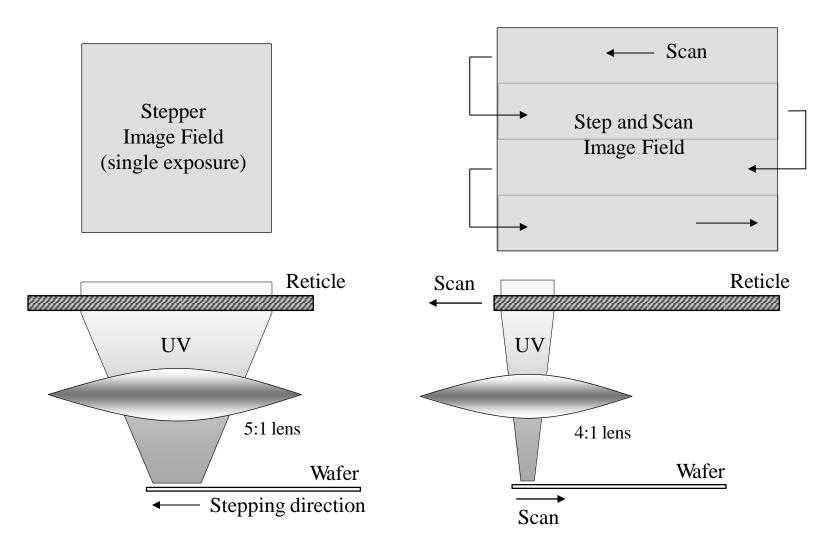


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Stepper Exposure Field

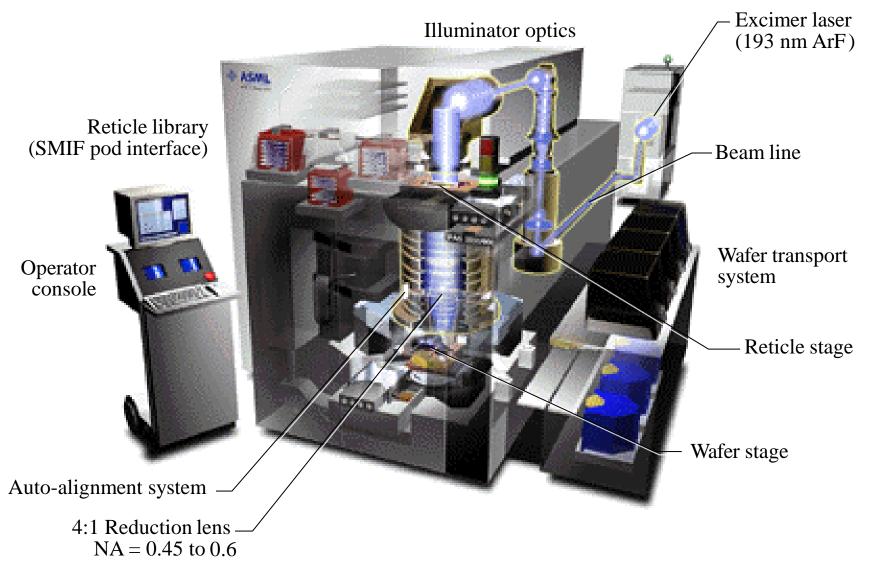


Wafer Exposure Field for Step-and-Scan



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Step and Scan Exposure System

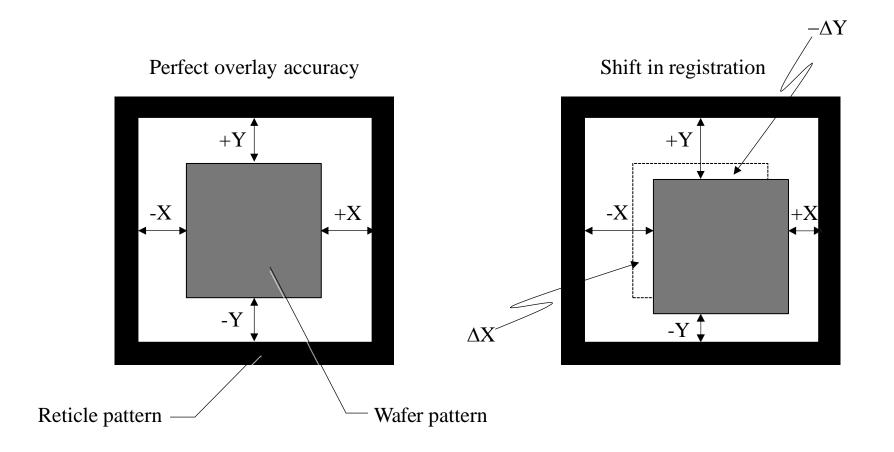


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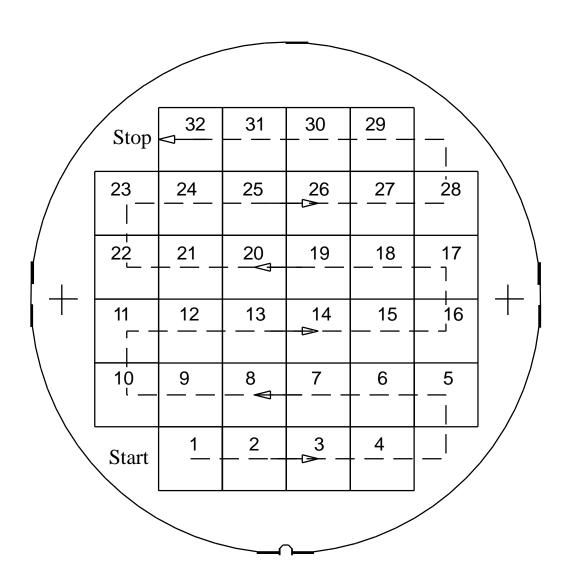
Alignment

- Baseline Compensation
- Overlay Accuracy
- Alignment Marks
- Types of Alignment

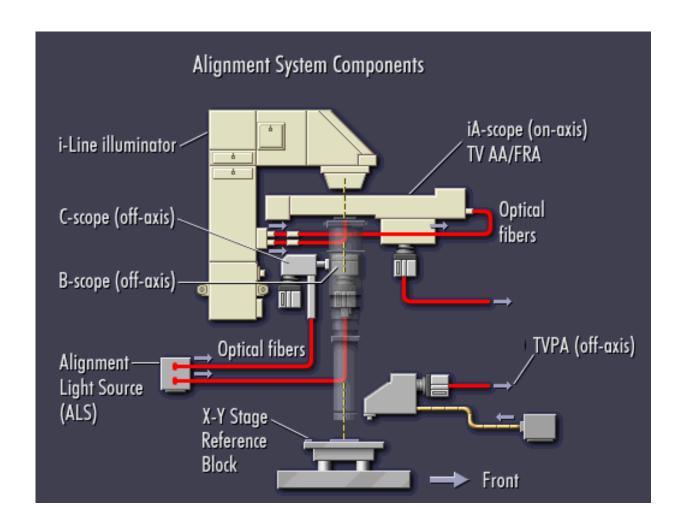
Overlay Budget



Grid of Exposure Fields on Wafer

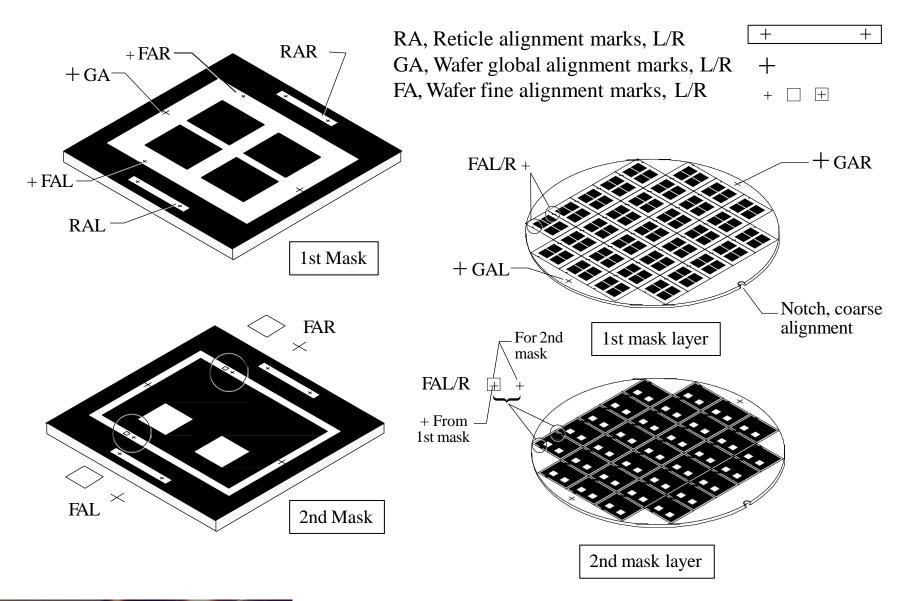


Step-and-Repeat Alignment System



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Alignment Marks



Environmental Conditions

- Temperature
- Humidity
- Vibration
- Atmospheric Pressure
- Particle Contamination

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